## FEATURES

High Speed
$190 \mathrm{MHz},-3 \mathrm{~dB}$ bandwidth ( $\mathrm{G}=+1$ )
100 V/ $\mu \mathrm{s}$ slew rate
Low distortion
120 dBc @ 1 MHz SFDR
80 dBc @ 5 MHz SFDR
Selectable input crossover threshold
Low noise
$4.3 \mathrm{nV} / \sqrt{\mathrm{Hz}}$
$1.6 \mathrm{pA} / \sqrt{ } \mathrm{Hz}$
Low offset voltage: $\mathbf{9 0 0} \boldsymbol{\mu} \mathrm{V}$ max
Low power
6 mA supply current
Power-down disable feature
No phase reversal
Wide supply range: 2.7 V to 12 V
Small packaging: SOIC-8, SOT-23-6

## APPLICATIONS

## Filters

ADC drivers
Level shifting
Buffering
Professional video
Low voltage instrumentation

## GENERAL DESCRIPTION

The AD8027 ${ }^{1}$ is a high speed amplifier with rail-to-rail input and output that operates on low supply voltages and is optimized for high performance and wide dynamic signal range. The AD8027 has low noise ( $4.3 \mathrm{nV} / \sqrt{ } \mathrm{Hz}, 1.6 \mathrm{pA} / \sqrt{ } \mathrm{Hz}$ ) and low distortion. In applications that use a fraction of or the entire input dynamic range and require low distortion, the AD8027 is an ideal choice.

Many rail-to-rail input amplifiers have an input stage that switches from one differential pair to another as the input signal crosses a threshold voltage, which causes distortion. The AD8027 has a unique feature that allows the user to select the input crossover threshold voltage through the SELECT pin. This feature controls the voltage at which the complementary transistor input pairs switch. The AD8027 also has intrinsically low crossover distortion.

Rev. 0
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## CONNECTION DIAGRAMS



Figure 1. Connection Diagrams (Top View)

With its wide supply voltage range ( 2.7 V to 12 V ) and wide bandwidth ( 190 MHz ), the AD8027 amplifier is designed to work in a variety of applications where speed and performance are needed on low supply voltages. The high performance of the AD8027 is achieved with a quiescent current of only 8.5 mA maximum. A power-down disable feature is also available.

The AD8027 is available in SOIC-8 and SOT-23-6 packages. They are rated to work over the industrial temperature range of $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$. A dual version of this amplifier is under development and will be released as the AD8028.


Figure 2. SFDR vs. Output Amplitude

[^0]
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REVISION HISTORY
Revision 0: Initial Version

## AD8027-SPECIFICATIONS

Table 1. $V_{S}= \pm 5 \mathrm{~V}$ (@ $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ to midsupply, $\mathrm{G}=+1$, unless otherwise noted.)

| Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| DYNAMIC PERFORMANCE <br> -3 dB Bandwidth <br> Bandwidth for 0.1 dB Flatness <br> Slew Rate <br> Settling Time to 0.1\% | $\begin{aligned} & G=+1, V_{o}=0.2 \mathrm{~V} \text { p-p } \\ & G=+1, V_{o}=2 \mathrm{~V} p-\mathrm{p} \\ & \mathrm{G}=+2, \mathrm{~V}_{\mathrm{o}}=0.2 \mathrm{~V} \text { p-p } \\ & \mathrm{G}=+1, \mathrm{~V}_{\mathrm{o}}=2 \mathrm{~V} \text { Step } \\ & \mathrm{G}=-1, \mathrm{~V}_{0}=2 \mathrm{~V} \text { Step } \\ & \mathrm{G}=+2, \mathrm{~V}_{0}=2 \mathrm{~V} \text { Step } \end{aligned}$ | $\begin{aligned} & 138 \\ & 20 \end{aligned}$ | $\begin{aligned} & 190 \\ & 32 \\ & 16 \\ & 90 \\ & 100 \\ & 35 \end{aligned}$ |  | MHz <br> MHz <br> MHz <br> V/us <br> V/us <br> ns |
| NOISE/DISTORTION PERFORMANCE <br> Spurious Free Dynamic Range (SFDR) <br> Input Voltage Noise <br> Input Current Noise <br> Differential Gain Error <br> Differential Phase Error | $\begin{aligned} & \mathrm{f}_{\mathrm{C}}=1 \mathrm{MHz}, \mathrm{~V}_{\mathrm{o}}=2 \mathrm{~V} \mathrm{p}-\mathrm{p}, \mathrm{R}_{\mathrm{F}}=24.9 \Omega \\ & \mathrm{f}_{\mathrm{C}}=5 \mathrm{MHz}, \mathrm{~V}_{\mathrm{o}}=2 \mathrm{~V}-\mathrm{p}, \mathrm{R}_{\mathrm{F}}=24.9 \Omega \\ & \mathrm{f}=100 \mathrm{kHz} \\ & \mathrm{f}=100 \mathrm{kHz} \\ & \text { NTSC, } \mathrm{G}=+2, \mathrm{R}_{\mathrm{L}}=150 \Omega \\ & \text { NTSC, G }=+2, \mathrm{R}_{\mathrm{L}}=150 \Omega \end{aligned}$ |  | $\begin{aligned} & 120 \\ & 80 \\ & 4.3 \\ & 1.6 \\ & 0.10 \\ & 0.20 \\ & \hline \end{aligned}$ |  | dBc <br> dBc <br> $\mathrm{nV} / \sqrt{ } \mathrm{Hz}$ <br> $\mathrm{pA} / \sqrt{ } \mathrm{Hz}$ <br> \% <br> Degree |
| DC PERFORMANCE Input Offset Voltage Input Offset Voltage Drift Input Bias Current ${ }^{1}$ Input Bias Current ${ }^{1}$ Input Offset Current Open-Loop Gain | SELECT = Tri-State or Open, PNP Active <br> SELECT = High NPN Active <br> $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ <br> $\mathrm{V}_{\mathrm{cm}}=0 \mathrm{~V}$, NPN Active <br> $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ <br> $V_{C M}=0$ V, PNP Active <br> $\mathrm{T}_{\text {Min }}$ to $\mathrm{T}_{\text {max }}$ $\mathrm{V}_{\mathrm{o}}= \pm 2.5 \mathrm{~V}$ |  | $\begin{aligned} & 200 \\ & 240 \\ & 1.50 \\ & 3.80 \\ & 4 \\ & -7.8 \\ & -8 \\ & \pm 0.1 \\ & 108 \end{aligned}$ | $\begin{aligned} & 800 \\ & 900 \\ & 5.50 \\ & -10.5 \\ & \pm 0.9 \end{aligned}$ | $\mu \mathrm{V}$ <br> $\mu \mathrm{V}$ <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> dB |
| INPUT CHARACTERISTICS <br> Input Impedance <br> Input Capacitance <br> Input Common-Mode Voltage Range Common-Mode Rejection Ratio | $\mathrm{V}_{\mathrm{CM}}= \pm 2.5 \mathrm{~V}$ | 90 | $\begin{aligned} & 6 \\ & 2 \\ & -5.2 \text { to }+5.2 \\ & 105 \end{aligned}$ |  | $\begin{aligned} & \mathrm{M} \Omega \\ & \mathrm{pF} \\ & \mathrm{~V} \\ & \mathrm{~dB} \end{aligned}$ |
| SELECT PIN <br> Crossover Low-Selection Input Voltage Crossover High—Selection Input Voltage Disable Input Voltage Disable Switching Speed Enable Switching Speed | Tri-State $< \pm 20 \mu \mathrm{~A}$ <br> $50 \%$ of Input to $<10 \%$ of Final $V_{\text {。 }}$ |  | $\begin{aligned} & -3.3 \text { to }+5 \\ & -3.9 \text { to }-3.3 \\ & -5 \text { to }-3.9 \\ & 980 \\ & 45 \end{aligned}$ |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \\ & \mathrm{~V} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| OUTPUT CHARACTERISTICS <br> Output Overdrive Recovery Time (Rising/Falling Edge) <br> Output Voltage Swing <br> Short Circuit Output <br> Off Isolation <br> Capacitive Load Drive | $\mathrm{V}_{1}=+6 \mathrm{~V} \text { to }-6 \mathrm{~V}, \mathrm{G}=-1$ <br> Sinking and Sourcing $\mathrm{V}_{\mathbb{I N}}=0.2 \mathrm{Vp}-\mathrm{p}, \mathrm{f}=1 \mathrm{MHz}, \text { SELECT }=\text { LOW }$ <br> 30\% Overshoot | $-\mathrm{V}_{\mathrm{s}}+0.10$ | $\begin{aligned} & 40 / 45 \\ & 120 \\ & -49 \\ & 20 \end{aligned}$ | + $\mathrm{V}_{\text {s }}-0.10$ | ns <br> V <br> mA <br> dB <br> pF |
| POWER SUPPLY <br> Operating Range <br> Quiescent Current <br> Quiescent Current (Disabled) <br> Power Supply Rejection Ratio | $\begin{aligned} & \text { SELECT = Low } \\ & \mathrm{V}_{\mathrm{s}} \pm 1 \mathrm{~V} \end{aligned}$ | 2.7 <br> 90 | $\begin{aligned} & 6.5 \\ & 370 \\ & 107 \end{aligned}$ | $\begin{aligned} & 12 \\ & 8.5 \\ & 500 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~mA} \\ & \mu \mathrm{~A} \\ & \mathrm{~dB} \end{aligned}$ |

${ }^{1}$ No sign or a plus indicates current into pin, minus indicates current out of pin.

## AD8027

## AD8027—SPECIFICATIONS

Table 2. $\mathrm{V}_{\mathrm{S}}=+5 \mathrm{~V}$ ( $\mathrm{C}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ to midsupply, unless otherwise noted.)

| Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| DYNAMIC PERFORMANCE <br> -3 dB Bandwidth <br> Bandwidth for 0.1 dB Flatness <br> Slew Rate <br> Settling Time to 0.1\% | $\begin{aligned} & \mathrm{G}=+1, \mathrm{~V}_{\mathrm{O}}=0.2 \mathrm{~V} \text { p-p } \\ & \mathrm{G}=+1, \mathrm{~V}_{\mathrm{O}}=2 \mathrm{~V} \text { p-p } \\ & \mathrm{G}=+2, \mathrm{~V}_{\mathrm{O}}=0.2 \mathrm{~V} \text { p-p } \\ & \mathrm{G}=+1, \mathrm{~V}_{\mathrm{O}}=2 \mathrm{~V} \text { Step } \\ & \mathrm{G}=-1, \mathrm{~V}_{\mathrm{O}}=2 \mathrm{~V} \text { Step } \\ & \mathrm{G}=+2, \mathrm{~V}_{\mathrm{O}}=2 \mathrm{~V} \text { Step } \end{aligned}$ | $\begin{aligned} & 131 \\ & 18 \end{aligned}$ | $\begin{aligned} & 185 \\ & 28 \\ & 12 \\ & 85 \\ & 100 \\ & 40 \end{aligned}$ |  | MHz <br> MHz <br> MHz <br> V/ $\mu \mathrm{s}$ <br> $\mathrm{V} / \mu \mathrm{s}$ <br> ns |
| NOISE/DISTORTION PERFORMANCE <br> Spurious Free Dynamic Range (SFDR) <br> Input Voltage Noise <br> Input Current Noise <br> Differential Gain Error <br> Differential Phase Error | $\begin{aligned} & \mathrm{f}_{\mathrm{C}}=1 \mathrm{MHz}, \mathrm{~V}_{\mathrm{O}}=2 \mathrm{~V} p-\mathrm{p}, \mathrm{R}_{\mathrm{F}}=24.9 \Omega \\ & \mathrm{f}_{\mathrm{C}}=5 \mathrm{MHz}, \mathrm{~V}_{\mathrm{O}}=2 \mathrm{Vp}-\mathrm{p}, \mathrm{R}_{\mathrm{F}}=24.9 \Omega \\ & \mathrm{f}=100 \mathrm{kHz} \\ & \mathrm{f}=100 \mathrm{kHz} \\ & \text { NTSC, } \mathrm{G}=+2, \mathrm{R}_{\mathrm{L}}=150 \Omega \\ & \text { NTSC, } \mathrm{G}=+2, \mathrm{R}_{\mathrm{L}}=150 \Omega \end{aligned}$ |  | $\begin{aligned} & 90 \\ & 64 \\ & 4.3 \\ & 1.6 \\ & 0.10 \\ & 0.20 \end{aligned}$ |  | dBc <br> dBc <br> $\mathrm{nV} / \sqrt{ } \mathrm{Hz}$ <br> $\mathrm{pA} / \sqrt{ } \mathrm{Hz}$ <br> \% <br> Degree |
| DC PERFORMANCE <br> Input Offset Voltage <br> Input Offset Voltage Drift Input Bias Current ${ }^{1}$ <br> Input Bias Current ${ }^{1}$ <br> Input Offset Current Open-Loop Gain | SELECT = Tri-State or Open, PNP Active <br> SELECT = High NPN Active <br> $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ <br> $\mathrm{V}_{\mathrm{CM}}=2.5 \mathrm{~V}$, NPN Active <br> $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ <br> $\mathrm{V}_{\mathrm{CM}}=2.5 \mathrm{~V}$, PNP Active <br> $\mathrm{T}_{\text {MIN }}$ to $\mathrm{T}_{\text {MAX }}$ $\mathrm{V}_{\mathrm{o}}=1 \mathrm{~V} \text { to } 4 \mathrm{~V}$ |  | $\begin{aligned} & 200 \\ & 240 \\ & 1.5 \\ & 3.7 \\ & 4 \\ & -7.8 \\ & -7.9 \\ & \pm 0.1 \\ & 105 \end{aligned}$ | $\begin{aligned} & 800 \\ & 900 \\ & \\ & 5.5 \\ & -10.5 \\ & \pm 0.9 \end{aligned}$ | $\mu \mathrm{V}$ <br> $\mu \mathrm{V}$ <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ <br> dB |
| INPUT CHARACTERISTICS <br> Input Impedance <br> Input Capacitance <br> Input Common-Mode Voltage Range Common-Mode Rejection Ratio | $\mathrm{V}_{\mathrm{CM}}=0 \mathrm{~V}$ to 2.5 V | 90 | $\begin{aligned} & 6 \\ & 2 \\ & -0.2 \text { to }+5.2 \\ & 105 \end{aligned}$ |  | $\mathrm{M} \Omega$ pF V dB |
| SELECT PIN <br> Crossover Low—Selection Input Voltage Crossover High—Selection Input Voltage Disable Input Voltage DISABLE Switching Speed Enable Switching Speed | Tri-State $< \pm 20 \mu \mathrm{~A}$ <br> $50 \%$ of Input to $<10 \%$ of Final $V_{0}$ |  | $\begin{aligned} & 1.7 \text { to } 5 \\ & 1.1 \text { to } 1.7 \\ & 0 \text { to } 1.1 \\ & 1100 \\ & 50 \end{aligned}$ |  | V <br> V <br> V ns ns |
| OUTPUT CHARACTERISTICS <br> Overdrive Recovery Time (Rising/Falling Edge) <br> Output Voltage Swing <br> Off Isolation <br> Short Circuit Current <br> Capacitive Load Drive | $\mathrm{V}_{1}=-1 \mathrm{~V} \text { to }+6 \mathrm{~V}, \mathrm{G}=-1$ $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega \\ & \mathrm{~V}_{\mathrm{IN}}=0.2 \mathrm{Vp}-\mathrm{p}, \mathrm{f}=1 \mathrm{MHz}, \text { SELECT }=\mathrm{LOW} \end{aligned}$ <br> Sinking and Sourcing <br> 30\% Overshoot | $-\mathrm{V}_{s}+0.08$ | $\begin{aligned} & 50 / 50 \\ & \\ & -49 \\ & 105 \\ & 20 \end{aligned}$ | $+\mathrm{V}_{s}-0.08$ | ns <br> V <br> dB <br> mA <br> pF |
| POWER SUPPLY <br> Operating Range <br> Quiescent Current <br> Quiescent Current (Disabled) <br> Power Supply Rejection Ratio | $\begin{aligned} & \text { SELECT = Low } \\ & \mathrm{V}_{\mathrm{s} \pm 1 \mathrm{~V}} \end{aligned}$ | $\begin{aligned} & 2.7 \\ & 90 \end{aligned}$ | $\begin{aligned} & 6 \\ & 320 \\ & 107 \end{aligned}$ | $\begin{aligned} & 12 \\ & 8.5 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~mA} \\ & \mu \mathrm{~A} \\ & \mathrm{~dB} \end{aligned}$ |

${ }^{1}$ No sign or a plus indicates current into pin, minus indicates current out of pin.

## AD8027-SPECIFICATIONS

Table 3. $V_{s}=+3 \mathrm{~V}$ ( $@ \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ to midsupply, unless otherwise noted.)

| Parameter | Conditions | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| DYNAMIC PERFORMANCE <br> -3 dB Bandwidth <br> Bandwidth for 0.1 dB Flatness <br> Slew Rate <br> Settling Time to 0.1\% | $\begin{aligned} & G=+1, V_{0}=0.2 \mathrm{~V} p-p \\ & G=+1, V_{0}=2 \mathrm{Vp}-\mathrm{p} \\ & \mathrm{G}=+2, \mathrm{~V}_{0}=0.2 \mathrm{~V} p-\mathrm{p} \\ & \mathrm{G}=+1, \mathrm{~V}_{0}=2 \mathrm{~V} \text { Step } \\ & \mathrm{G}=-1, \mathrm{~V}_{0}=2 \mathrm{~V} \text { Step } \\ & \mathrm{G}=+2, \mathrm{~V}_{0}=2 \mathrm{~V} \text { Step } \end{aligned}$ | $\begin{aligned} & 125 \\ & 19 \end{aligned}$ | $\begin{aligned} & 180 \\ & 29 \\ & 10 \\ & 73 \\ & 100 \\ & 48 \\ & \hline \end{aligned}$ |  | MHz <br> MHz <br> MHz <br> V/ $\mu \mathrm{s}$ <br> $\mathrm{V} / \mu \mathrm{s}$ ns |
| NOISE/DISTORTION PERFORMANCE <br> Spurious Free Dynamic Range (SFDR) <br> Input Voltage Noise <br> Input Current Noise <br> Differential Gain Error <br> Differential Phase Error | $\begin{aligned} & \mathrm{f}_{\mathrm{C}}=1 \mathrm{MHz}, \mathrm{~V}_{\mathrm{o}}=2 \mathrm{~V} \mathrm{p}-\mathrm{p}, \mathrm{R}_{\mathrm{F}}=24.9 \Omega \\ & \mathrm{f}_{\mathrm{C}}=5 \mathrm{MHz}, \mathrm{~V}_{\mathrm{o}}=2 \mathrm{~V}-\mathrm{p}, \mathrm{R}_{\mathrm{F}}=24.9 \Omega \\ & \mathrm{f}=100 \mathrm{kHz} \\ & \mathrm{f}=100 \mathrm{kHz} \\ & \text { NTSC, G }=+2, \mathrm{R}_{\mathrm{L}}=150 \Omega \\ & \text { NTSC, G }=+2, \mathrm{R}_{\mathrm{L}}=150 \Omega \end{aligned}$ |  | $\begin{aligned} & 85 \\ & 64 \\ & 4.3 \\ & 1.6 \\ & 0.15 \\ & 0.20 \\ & \hline \end{aligned}$ |  | dBc <br> dBc <br> $\mathrm{nV} / \sqrt{ } \mathrm{Hz}$ <br> $\mathrm{pA} / \sqrt{ } \mathrm{Hz}$ <br> \% <br> Degree |
| DC PERFORMANCE Input Offset Voltage Input Offset Voltage Drift Input Bias Current ${ }^{1}$ Input Bias Current ${ }^{1}$ Input Offset Current Open-Loop Gain | SELECT = Tri-State or Open, PNP Active <br> SELECT = High NPN Active <br> $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ <br> $V_{c m}=1.5 \mathrm{~V}$, NPN Active <br> $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ <br> $V_{C M}=1.5 \mathrm{~V}$, PNP Active <br> $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ $V_{0}=1 \mathrm{~V} \text { to } 2 \mathrm{~V}$ |  | $\begin{aligned} & 200 \\ & 240 \\ & 1.5 \\ & 3.5 \\ & 3.8 \\ & -7.5 \\ & -7.7 \\ & \pm 0.1 \\ & 100 \end{aligned}$ | $\begin{aligned} & 800 \\ & 900 \\ & 5.5 \\ & -10.5 \\ & \pm 0.9 \end{aligned}$ | $\mu \mathrm{V}$ $\mu \mathrm{V}$ $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ $\mu \mathrm{A}$ $\mu \mathrm{A}$ $\mu \mathrm{A}$ $\mu \mathrm{A}$ $\mu \mathrm{A}$ dB |
| INPUT CHARACTERISTICS <br> Input Impedance <br> Input Capacitance <br> Input Common-Mode Voltage Range <br> Common-Mode Rejection Ratio | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega \\ & \mathrm{~V}_{\mathrm{CM}}=0 \mathrm{~V} \text { to } 1.5 \mathrm{~V} \end{aligned}$ | 88 | $\begin{aligned} & 6 \\ & 2 \\ & -0.2 \text { to }+3.2 \\ & 100 \end{aligned}$ |  | $\mathrm{M} \Omega$ <br> pF <br> V <br> dB |
| SELECT PIN <br> Crossover Low-Selection Input Voltage Crossover High—Selection Input Voltage Disable Input Voltage DISABLE Switching Speed Enable Switching Speed | Tri-State $< \pm 20 \mu \mathrm{~A}$ <br> $50 \%$ of Input to $<10 \%$ of Final $V_{0}$ |  | 1.7 to 3 <br> 1.1 to 1.7 <br> 0 to 1.1 <br> 1150 <br> 50 |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \\ & \mathrm{~V} \\ & \mathrm{~ns} \\ & \mathrm{~ns} \end{aligned}$ |
| OUTPUT CHARACTERISTICS <br> Output Overdrive Recovery Time (Rising/Falling Edge) <br> Output Voltage Swing <br> Short Circuit Current <br> Off Isolation <br> Capacitive Load Drive | $\begin{aligned} & \mathrm{V}_{\mathrm{L}}=-1 \mathrm{~V} \text { to }+4 \mathrm{~V}, \mathrm{G}=-1 \\ & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega \end{aligned}$ <br> Sinking and Sourcing $\mathrm{V}_{\text {IN }}=0.2 \mathrm{Vp-p,f=} 1 \mathrm{MHz}, \text { SELECT }=\text { LOW }$ <br> 30\% Overshoot | $-\mathrm{V}_{s}+0.07$ | $55 / 55$ 72 -49 20 | $+\mathrm{V}_{5}-0.07$ | ns <br> V <br> mA <br> dB <br> pF |
| POWER SUPPLY <br> Operating Range <br> Quiescent Current <br> Quiescent Current (Disabled) <br> Power Supply Rejection Ratio | $\begin{aligned} & \text { SELECT = Low } \\ & \mathrm{V}_{\mathrm{s}} \pm 1 \mathrm{~V} \end{aligned}$ | 2.7 | $\begin{aligned} & 6.0 \\ & 300 \\ & 100 \\ & \hline \end{aligned}$ | $\begin{aligned} & 12 \\ & 8.0 \\ & 420 \end{aligned}$ | mA <br> $\mu \mathrm{A}$ <br> dB |

${ }^{1}$ No sign or a plus indicates current into pin, minus indicates current out of pin.

ABSOLUTE MAXIMUM RATINGS
Table 4.

| Parameter | Rating |
| :--- | :--- |
| Supply Voltage | 12.6 V |
| Power Dissipation | See Figure 3 |
| Common-Mode Input Voltage | $\pm \mathrm{V}_{\mathrm{s}} \pm 0.5 \mathrm{~V}$ |
| Differential Input Voltage | $\pm 1.8 \mathrm{~V}$ |
| Storage Temperature | $-65^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Operating Temperature Range | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Lead Temperature Range <br> (Soldering 10 sec) | $300^{\circ} \mathrm{C}$ |
| Junction Temperature | $150^{\circ} \mathrm{C}$ |
| Stresses above those listed under Absolute Maximum Ratings <br> may cause permanent damage to the device. This is a stress <br> rating only; functional operation of the device at these or any <br> other conditions above those indicated in the operational <br> section of this specification is not implied. Exposure to absolute <br> maximum rating conditions for extended periods may affect <br> device reliability. |  |

## Maximum Power Dissipation

The maximum safe power dissipation in the AD8027 package is limited by the associated rise in junction temperature $\left(T_{J}\right)$ on the die. The plastic encapsulating the die will locally reach the junction temperature. At approximately $150^{\circ} \mathrm{C}$, which is the glass transition temperature, the plastic will change its properties. Even temporarily exceeding this temperature limit may change the stresses that the package exerts on the die, permanently shifting the parametric performance of the AD8027. Exceeding a junction temperature of $175^{\circ} \mathrm{C}$ for an extended period of time can result in changes in the silicon devices, potentially causing failure.

The still-air thermal properties of the package and $\operatorname{PCB}\left(\theta_{\mathrm{JA}}\right)$, ambient temperature $\left(\mathrm{T}_{\mathrm{A}}\right)$, and the total power dissipated in the package $\left(\mathrm{P}_{\mathrm{D}}\right)$ determine the junction temperature of the die. The junction temperature can be calculated as:

$$
T_{J}=T_{A}+\left(P_{D} \times \theta_{J A}\right)
$$

The power dissipated in the package $\left(\mathrm{P}_{\mathrm{D}}\right)$ is the sum of the quiescent power dissipation and the power dissipated in the package due to the load drive for all outputs. The quiescent power is the voltage between the supply pins $\left(\mathrm{V}_{s}\right)$ times the quiescent current $\left(\mathrm{I}_{\mathrm{s}}\right)$. Assuming the load $\left(\mathrm{R}_{\mathrm{L}}\right)$ is referenced to midsupply, then the total drive power is $\mathrm{V}_{\mathrm{s}} / 2 \times$ Iout, some of which is dissipated in the package and some in the load $\left(\mathrm{V}_{\text {out }} \times\right.$ Iout $)$. The difference between the total drive power and the load power is the drive power dissipated in the package.

$$
\begin{gathered}
P_{D}=\text { Quiescent Power }+(\text { Total Drive Power }- \text { Load Power }) \\
\qquad P_{D}=\left(V_{S} \times I_{S}\right)+\left(\frac{V_{S}}{2} \times \frac{V_{\text {OUT }}}{R_{L}}\right)-\frac{V_{\text {OUT }}{ }^{2}}{R_{L}}
\end{gathered}
$$

RMS output voltages should be considered. If $R_{L}$ is referenced to $\mathrm{V}_{\mathrm{s} \text {-, as }}$ in single-supply operation, then the total drive power is $\mathrm{V}_{\mathrm{S}} \times$ Iout.

If the rms signal levels are indeterminate, then consider the worst case, when $V_{\text {out }}=V_{S} / 4$ for $\mathrm{R}_{\mathrm{L}}$ to midsupply

$$
P_{D}=\left(V_{S} \times I_{S}\right)+\frac{\left(V_{S} / 4\right)^{2}}{R_{L}}
$$

In single-supply operation with $\mathrm{R}_{\mathrm{L}}$ referenced to $\mathrm{V}_{\mathrm{S}^{-}}$, worst case is $V_{\text {out }}=V_{s} / 2$.

Airflow will increase heat dissipation, effectively reducing $\theta_{\mathrm{JA}}$. Also, more metal directly in contact with the package leads from metal traces, through holes, ground, and power planes will reduce the $\theta_{\mathrm{JA}}$. Care must be taken to minimize parasitic capacitances at the input leads of high speed op amps as discussed in the board layout section.

Figure 3 shows the maximum safe power dissipation in the package versus the ambient temperature for the SOIC-8 $\left(125^{\circ} \mathrm{C} / \mathrm{W}\right)$ and SOT-23-6 $\left(170^{\circ} \mathrm{C} / \mathrm{W}\right)$ packages on a JEDEC standard 4-layer board. $\theta_{\mathrm{IA}}$ values are approximations.

## OUTPUT SHORT CIRCUIT

Shorting the output to ground or drawing excessive current for the AD8027 will likely cause catastrophic failure.


Figure 3. Maximum Power Dissipation

## TYPICAL PERFORMANCE CHARACTERISTICS

Default Conditions $V_{S}=+5 \mathrm{~V}\left(\mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega\right.$, unless otherwise noted.)


Figure 4. Small Signal Frequency Response for Various Gains


Figure 5. Small Signal Frequency Response for Various Supplies


Figure 6. Large Signal Frequency Response for Various Supplies


Figure 7. 0.1 dB Flatness Frequency Response


Figure 8. Small Signal Frequency Response for Various Supplies


Figure 9. Large Signal Frequency Response for Various Supplies


Figure 10. Small Signal Frequency Response for Various C LOAD


Figure 11. Frequency Response for Various Output Amplitudes


Figure 12. Small Signal Frequency Response vs. Temperature


Figure 13. Small Signal Frequency Response for Various Input Common-Mode Votlages


Figure 14. Small Signal Frequency Response for Various R LOAD Values


Figure 15. Open-Loop Gain and Phase vs. Frequency


Figure 16. Harmonic Distortion vs. Frequency and Supply Voltage


Figure 17. Harmonic Distortion vs. Output Amplitude


Figure 18. Harmonic Distortion vs. Input Common-Mode Voltage, SELECT $=$ High


Figure 19. Harmonic Distortion vs. Frequency and Load


Figure 20. Harmonic Distortion vs. Input Common-Mode Voltage, $V_{s}=+5 \mathrm{~V}$


Figure 21. Harmonic Distortion vs. Input Common-Mode Voltage, SELECT = Tri-State or Open


Figure 22. Harmonic Distortion vs. Frequency and Gain


Figure 23. Small Signal Transient Response


Figure 24. Large Signal Transient Response, $G=+1$


Figure 25. Large Signal Transient Response, $G=+2$


Figure 26. Small Signal Transient Response with Capacitive Load


Figure 27. Output Overdrive Recovery


Figure 28. Input Overdrive Recovery


Figure 29. Long-Term Settling Time


Figure 30. 0.1\% Short-Term Settling Time


Figure 31. Input Bias Current vs. Temperature


Figure 32. Input Bias Current vs. Input Common-Mode Voltage


Figure 33. Input Offset Voltage Distribution


Figure 34. Input Offset Voltage vs. Temperature


Figure 35. Input Offset Voltage vs. Input Common-Mode Voltage, $V_{s}= \pm 5$


Figure 36. Input Offset Voltage vs. Input Common-Mode Voltage, Vs $=+5$


Figure 37. Input Offset Voltage vs. Input Common-Mode Voltage, $V_{S}=+3$


Figure 38. CMRR vs. Frequency


Figure 39. PSRR vs. Frequency


Figure 40. Voltage and Current Noise vs. Frequency


Figure 41. Off Isolation vs. Frequency


Figure 42. Output Saturation Voltage vs. Output Load


Figure 43. Output Saturation Voltage vs. Temperature


Figure 44. Open-Loop Gain vs. Load Current


Figure 45. Output Disabled-Impedance vs. Frequency


Figure 46. Output Enabled-Impedance vs. Frequency


Figure 47. SELECT Pin Current vs. SELECT Pin Voltage and Temperature


Figure 48. Enable Turn On Timing


Figure 49. Disable Turn Off Timing


Figure 50. Quiescent Supply Current vs. Supply Voltage and Temperature

## THEORY OF OPERATION

The AD8027 is a rail-to-rail input and output amplifier designed in Analog Devices XFCB process. The XFCB process enables the AD8027 to run on 2.7 V to 12 V supplies with 190 MHz of bandwidth and over $100 \mathrm{~V} / \mu \mathrm{s}$ of slew rate. The AD8027 has $4.3 \mathrm{nV} / \sqrt{ } \mathrm{Hz}$ of wideband noise with $17 \mathrm{nV} / \sqrt{ } \mathrm{Hz}$ noise at 10 Hz . This noise performance, with an offset and drift performance of less than $900 \mu \mathrm{~V}$ maximum and $1.5 \mu \mathrm{~V} /{ }^{\circ} \mathrm{C}$ typical , respectively, makes the AD8027 ideal for high speed precision applications. Additionally, the input stage operates 200 mV beyond the supply rails and shows no phase reversal. The amplifier features over voltage protection on the input stage. Once the inputs exceed the supply rails by 0.7 V , ESD protection diodes will turn on, drawing excessive current through the differential input pins. A series input resistor should be included to limit the input current to less than 10 mA .

## Input Stage

The rail-to-rail input performance is achieved by operating complementary input pairs. Which pair is on is determined by the common-mode level of the differential input signal. Looking at the schematic in Figure 51, a tail current ( $\mathrm{I}_{\text {tail }}$ ) is generated that sources the PNP differential input structure consisting of Q1 and Q2. A reference voltage is generated internally that is connected to the base of Q5. This voltage is continually compared against the common-mode input voltage. When the common-mode level exceeds the internal reference voltage, Q5 diverts the tail current ( $\mathrm{I}_{\text {TAIL }}$ ) from the PNP input pair to a current mirror that sources the NPN input pair consisting of Q3 and Q4. The NPN input pair can now operate 200 mV above
the positive rail. Both input pairs are protected from differential input signals above 1.4 V by four diodes across the input (see Figure 51). In the event of differential input signals that exceed 1.4 V , the diodes will conduct and excessive current will flow through them. A series input resistor should be included to limit the input current to 10 mA .

## Crossover Selection

A new feature available on the AD8027, which is called Crossover Selection, allows the user to choose the crossover point between the PNP/NPN differential pairs. Although the crossover region is small, operating in this region should be avoided since it can introduce offset and distortion to the output signal. To help avoid operating in the crossover region, the AD8027 allows the user to select from two preset crossover locations (i.e., voltage levels) using the SELECT pin. Looking at the schematic in Figure 51, the crossover region is about 200 mV and is defined by the voltage level at the base of Q5. Internally, two separate voltage sources are created approximately 1.2 V from either rail. One or the other is connected to Q5 based on the voltage applied to the SELECT pin. This allows for either dominant PNP pair operation, when the SELECT pin is left open, or dominant NPN pair operation, when the SELECT pin is pulled high. This pin also provides the traditional power-down function when it is pulled low. This allows the designer to achieve the best precision and ac performance for high-side and low-side signal applications. See Figure 45 through Figure 49 for SELECT pin characteristics.


Figure 51. Simplified Input Stage

## AD8027

In the event that the crossover region cannot be avoided, specific attention has been given to the input stage to ensure constant transconductance and minimal offset in all regions of operation. The regions are: PNP input pair running, NPN input pair running, and both running at the same time (in the 200 mV crossover region). Maintaining constant transconductance in all regions ensures the best wideband distortion performance when going between these regions. With this technique the AD8027 can achieve greater than 80 dB SFDR for a 2 V p-p, $1 \mathrm{MHz}, \mathrm{G}=+1$ signal on $\pm 1.5 \mathrm{~V}$ supplies. Another requirement in achieving this level of distortion is the offset of each pair must be laser trimmed to achieve greater than 80 dB SFDR, even for low frequency signals.

## Output Stage

The AD8027 uses a common-emitter output structure to achieve rail-to-rail output capability. The output stage is designed to drive 50 mA of linear output current, 40 mA within 200 mV of the rail, and 2.5 mA within 35 mV of the rail. Loading of the output stage, including any possible feedback network, will lower the open-loop gain of the amplifier. Refer to Figure 44 for the loading behavior. Capacitive load can degrade the phase margin of the amplifier. The AD8027 can drive up to $20 \mathrm{pF}, \mathrm{G}=+1$ as seen in Figure 10. A series resistor ( $\mathrm{R}_{\mathrm{SNUB}}$ ) should be included if the capacitive load is to exceed 20 pF for a gain of one. A small series output resistor ( $25 \Omega$ to $50 \Omega$ ) should be used if the capacitive load exceeds 20 pF . Increasing the closed-loop gain will increase the amount of capacitive load that can be driven before a series resistor will need to be included.

## DC Errors

The AD8027 uses two complementary input stages to achieve rail-to-rail input performance as mentioned in the Input Stage section. To use the dc performance over the entire commonmode range, the input bias current and input offset voltage of each pair must be considered.

Referring to Figure 52, the output offset voltage of each pair is calculated by

$$
\begin{aligned}
& V_{\mathrm{OS}, \mathrm{PNP,OUT}}=\mathrm{V}_{\mathrm{OS,PNP}}\left(\frac{\mathrm{R}_{\mathrm{G}}+\mathrm{R}_{\mathrm{F}}}{\mathrm{R}_{\mathrm{G}}}\right), \\
& \mathrm{V}_{\mathrm{OS}, \mathrm{NPN,OUT}}=\mathrm{V}_{\mathrm{OS}, \mathrm{NPN}}\left(\frac{\mathrm{R}_{\mathrm{G}}+\mathrm{R}_{\mathrm{F}}}{\mathrm{R}_{\mathrm{G}}}\right)
\end{aligned}
$$

where the difference of the two will be the discontinuity experienced when going through the crossover region. The size of the discontinuity is defined as

$$
V_{D I S}=\left(V_{O S, P N P}-V_{O S, N P N}\right)\left(\frac{R_{G}+R_{F}}{R_{G}}\right)
$$

Using the crossover select feature of the AD8027 helps to avoid this region. In the event that the region cannot be avoided, the quantity $\left(V_{O S, P N P}-V_{O S, N P N}\right)$ is trimmed to minimize this effect.

Because the input pairs are complementary, the input bias current will reverse polarity when going through the crossover region shown in Figure 32. The offset between pairs is described by

$$
V_{O S, P N P}-V_{O S, N P N}=\left(l_{B, P N P}-I_{B, N P N}\right) \times\left[R_{S}\left(\frac{R_{G}+R_{F}}{R_{G}}\right)-R_{F}\right]
$$

$\mathrm{I}_{\mathrm{B}, \mathrm{PNP}}$ is the input bias current of either input when the PNP input pair is active, and $I_{B, N P N}$ is the input bias current or either input pair when the NPN pair is active. If $R_{S}$ is sized so that when multiplied by the gain factor it equals $\mathrm{R}_{\mathrm{F}}$, this effect will be eliminated. It is strongly recommended to balance the impedances in this manner when traveling through the crossover region to minimize the dc error and distortion. As an example, assuming the PNP input pair has an input bias current of $6 \mu \mathrm{~A}$ and the NPN input pair has an input bias current of $-2 \mu \mathrm{~A}$, a $200 \mu \mathrm{~V}$ shift in offset will occur when traveling through the crossover region with $\mathrm{R}_{\mathrm{F}}$ equal to $0 \Omega$ and $\mathrm{R}_{\mathrm{s}}$ equal to $25 \Omega$.

In addition to the input bias current shift between pairs, each input pair has an input bias current offset that will contribute to the total offset in the following manner

$$
\Delta V_{O S}=I_{B+} R_{S}\left(\frac{R_{G}+R_{F}}{R_{G}}\right)-I_{B-} R_{F}
$$



Figure 52. Op Amp DC Error Sources

## WIDEBAND OPERATION

Voltage feedback amplifiers can use a wide range of resistor values to set their gain. Proper design of the application's feedback network requires consideration of the following issues:

- Poles formed by the amplifier's input capacitances with the resistances seen at the amplifier's input terminals
- Effects of mismatched source impedances
- Resistor value impact on the application's voltage noise
- Amplifier loading effects

The AD8027 has an input capacitance of 2 pF . This input capacitance will form a pole with the amplifier's feedback network, destabilizing the loop. For this reason, it is generally desirable to keep the source resistances below $500 \Omega$, unless some capacitance is included in the feedback network. Likewise, keeping the source resistances low will also take advantage of the AD8027's low input referred voltage noise of $4.3 \mathrm{nV} / \sqrt{ } \mathrm{Hz}$.

With a wide bandwidth of over 190 MHz , the AD8027 has numerous applications and configurations. The AD8027 shown in Figure 53 is configured as a noninverting amplifier. The inverting configuration is shown in Figure 54 and an easy selection table of gain, resistor values, bandwidth, slew rate, and noise performance is presented in Table 5.


Figure 54. Wideband Inverting Gain Configuration

Table 5. Component Values, Bandwidth, and Noise Performance ( $\mathrm{V}_{\mathrm{s}}= \pm \mathbf{2 . 5} \mathrm{V}$ )

| Noise Gain <br> (Noninverting) | Rsource <br> $\mathbf{( \Omega )}$ | $\mathbf{R}_{\mathbf{F}}$ <br> $\mathbf{( \Omega )} \mathbf{)}$ | $\mathbf{R}_{\mathbf{G}}$ <br> $\mathbf{( \Omega )}$ | $\mathbf{- 3 ~ d B}$ <br> $\mathbf{S S}$ BW <br> $(\mathbf{M H z})$ | Output <br> Noise with <br> Resistors <br> $(\mathbf{n V} / \sqrt{ } / \mathbf{H z})$ |
| :--- | :--- | :--- | :--- | :--- | :--- |
| 1 | 50 | 0 | N/A | 190 | 4.4 |
| 2 | 50 | 499 | 499 | 95 | 10 |
| 10 | 50 | 499 | 54.9 | 13 | 45 |



Figure 53. Wideband Noninverting Gain Configuration

## Circuit Considerations

## Balanced Input Impedances

Balanced input impedances can help improve distortion performance. When the amplifier transitions from PNP pair to NPN pair operation, a change in both the magnitude and direction of the input bias current will occur. When multiplied times imbalanced input impedances, a change in offset will result. The key to minimizing this distortion is to keep the input impedances balanced on both inputs. Figure 55 shows the effect of the imbalance and degradation in distortion performance for a $50 \Omega$ source impedance, with and without a $50 \Omega$ balanced feedback path.


Figure 55. SFDR vs. Frequency and Various $R_{F}$

## PCB Layout

As with all high speed op amps, achieving optimum performance from the AD8027 requires careful attention to PCB layout. Particular care must be exercised to minimize lead lengths of the bypass capacitors. Excess lead inductance can influence the frequency response and even cause high frequency oscillations. The use of a multilayer board, with an internal ground plane, will reduce ground noise and enable a tighter layout.

To achieve the shortest possible lead length at the inverting input, the feedback resistor, $\mathrm{R}_{\mathrm{F}}$, should be located beneath the board and span the distance from the output, Pin 6, to the input, $\operatorname{Pin} 2$. The return node of the resistor $\mathrm{R}_{\mathrm{G}}$ should be situated as closely as possible to the return node of the negative supply bypass capacitor connected to Pin 4.

On multilayer boards, all layers underneath the op amp should
be cleared of metal to avoid creating parasitic capacitive elements. This is especially true at the summing junction (i.e., the -input). Extra capacitance at the summing junction can cause increased peaking in the frequency response and lower phase margin.

## Grounding

To minimize parasitic inductances and ground loops in high speed, densely populated boards, a ground plane layer is critical. Understanding where the current flows in a circuit is critical in the implementation of high speed circuit design. The length of the current path is directly proportional to the magnitude of the parasitic inductances and thus the high frequency impedance of the path. Fast current changes in an inductive ground return will create unwanted noise and ringing.

The length of the high frequency bypass capacitor pads and traces is critical. A parasitic inductance in the bypass grounding will work against the low impedance created by the bypass capacitor. Because load currents flow from supplies as well as ground, the load should be placed at the same physical location as the bypass capacitor ground. For large values of capacitors, which are intended to be effective at lower frequencies, the current return path length is less critical.

## Power Supply Bypassing

Power supply pins are actually inputs and care must be taken to provide a clean, low noise dc voltage source to these inputs. The bypass capacitors have two functions:

1. Provide a low impedance path for unwanted frequencies from the supply inputs to ground, thereby reducing the effect of noise on the supply lines.
2. Provide sufficient localized charge storage, for fast switching conditions and minimizing the voltage drop at the supply pins and the output of the amplifier. This is usually accomplished with larger electrolytic capacitors.

Decoupling methods are designed to minimize the bypassing impedance at all frequencies. This can be accomplished with a combination of capacitors in parallel to ground.

Good quality ceramic chip capacitors should be used and always kept as close to the amplifier package as possible. A parallel combination of a $0.01 \mu \mathrm{~F}$ ceramic and a $10 \mu \mathrm{~F}$ electrolytic covers a wide range of rejection for unwanted noise. The $10 \mu \mathrm{~F}$ capacitor is less critical for high frequency bypassing, and in most cases, one per supply line is sufficient.

## APPLICATIONS

## Using the AD8027 SELECT Pin

The AD8027 features a unique SELECT pin with two functions. The first is a power-down function that places the AD8027 into low power consumption mode. In the power-down mode, the amplifier draws $450 \mu \mathrm{~A}$ (typ) of supply current.

The second function, as mentioned in the Theory of Operation section, shifts the crossover point (where the NPN/PNP input differential pairs transition from one to the other) closer to either the positive supply rail or the negative supply rail. This selectable crossover point allows the user to minimize distortion based on the input signal and environment. The default state is 1.2 V from the positive power supply, with the SELECT pin left floating or in tri-state.

Table 6 shows the required voltages and modes of the SELECT pin.

Table 6. SELECT Pin Mode Control Table

| Mode | SELECT Pin Voltage (V) |  |  |
| :--- | :--- | :--- | :--- |
|  | $\mathrm{V}_{s}= \pm 5 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{s}}=+5 \mathrm{~V}$ | $\mathrm{~V}_{\mathrm{s}}=+3 \mathrm{~V}$ |
| Disable | -5 to -4.2 | 0 to 0.8 | 0 to 0.8 |
| Crossover Referenced <br> 1.2 V to Positive Supply | -4.2 to -3.3 | 0.8 to 1.7 | 0.8 to 1.7 |
| Crossover Referenced <br> 1.2 V to Negative Supply | -3.3 to +5 | 1.7 to 5.0 | 1.7 to 3.0 |

When the input stage transitions from one input differential pair to the other, there is virtually no noticeable change in the output waveform.

The disable time of the AD8027 amplifier is load dependent. Typical data is presented in Table 7, see Figure 48 and Figure 49 for the actual switching measurements.

Table 7. DISABLE Switching Speeds

|  | Supply Voltages ( $\left.\mathbf{R}_{\mathbf{L}}=\mathbf{1} \mathbf{~ k} \boldsymbol{\Omega}\right)$ |  |  |
| :--- | :--- | :--- | :--- |
|  | $\mathbf{+ 5} \mathbf{~ V}$ | $\mathbf{+ 5} \mathbf{~ V}$ | $\mathbf{+ 3} \mathbf{~ V}$ |
|  | 45 ns | 50 ns | 50 ns |
| toff | 980 ns | 1100 ns | 1150 ns |

## Driving a16-Bit ADC

With the adjustable crossover distortion selection point and low noise, the AD8027 is an ideal amplifier for driving or buffering input signals into high resolution ADCs, such as the AD7677. Figure 56 shows the typical schematic for driving the ADC. The AD8027, driving the AD7677, offers performance close to non-rail-to-rail amplifiers and avoids the need for an additional supply, other than the single 5 V supply already used
by the ADC. In this application, the SELECT pins are biased to avoid the crossover region of the AD8027 for low distortion operation.


Figure 56. Unity Gain Differential Drive
As seen in Figure 57, the AD8027/AD7677 combination offers excellent integral nonlinearity (INL). Summary test data for the schematic shown in Figure 56 is presented in Table 8.

Table 8. ADC Driver Performance, $\mathrm{f}_{\mathrm{c}}=100 \mathrm{KHz}, \mathrm{V}_{\text {out }}=4.7 \mathrm{~V}$ p-p

| Parameter | Measurement |
| :--- | :--- |
| Second Harmonic Distortion | -105 dB |
| Third Harmonic Distortion | -102 dB |
| THD | -102 dB |
| SFDR | 105 dBc |



Figure 57. Integral Nonlinearity

## AD8027

## Band-Pass Filter

In communication systems, active filters are used extensively in signal processing. The AD8027 is an excellent choice for active filter applications. In realizing this filter, it is important that the amplifier has a large signal bandwidth of at least $10 \times$ of the center frequency, fo, otherwise a phase shift can occur in the amplifier, causing instability and oscillations.

In the schematic shown in Figure 58, the AD8027 is configured as a 1 MHz band-pass filter. The target specifications are $\mathrm{f}_{\mathrm{o}}=1$ MHz and a -3 dB pass band of 500 kHz . When designing a band-pass filter, the designer must start by selecting the following: $\mathrm{f}_{\mathrm{o}}, \mathrm{Q}, \mathrm{C} 1$, and R 4 . Then using the equations shown below calculate the remaining variables.

The test data shown in Figure 59 indicates that this design yielded a filter response with a center frequency $f_{o}=1 \mathrm{MHz}$ and a bandwidth of 450 kHz .

$$
\begin{gathered}
Q=\frac{f_{o}(\mathrm{MHz})}{\operatorname{Pass} \operatorname{Band}(\mathrm{MHz})} \\
k=2 \pi f_{O} C 1 \\
C 2=0.5 \mathrm{C} 1 \\
R 1=2 / k, R 2=2 / 3 k, R 3=4 / k
\end{gathered}
$$

$$
H=1 / 3(6.5-1 / Q)
$$

$$
R 5=R 4 /(H-1)
$$



Figure 58. Band-Pass Filter Schematic


Figure 59. Band-Pass Filter Response

## Design Tools and Technical Support

Analog Devices is committed to simplifying the design process by providing technical support and online design tools. We offer technical support via free evaluation boards, sample ICs, interactive evaluation tools, datasheets, application notes, and phone and email support, which is all available at www. analog.com.

## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-012AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN
Figure 60. 8-Lead Standard Small Outline Package, Narrow Body [SOIC] (RN-8)—Dimensions shown in millimeters and (inches)


Figure 61. 6-Lead Plastic Surface-Mount Package [SOT-23] (RT-6) —Dimensions shown in millimeters

## ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance
degradation or loss of functionality.

## Ordering Guide

| AD8027 Products | Minimum Ordering <br> Quantity | Temperature <br> Range | Package <br> Description | Package <br> Outline | Branding <br> Information |
| :--- | :--- | :--- | :--- | :--- | :--- |
| AD8027AR | 1 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8 -Lead SOIC | RN-8 |  |
| AD8027AR-REEL | 1,000 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8 -Lead SOIC | RN-8 |  |
| AD8027AR-REEL7 | 400 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 8 -Lead SOIC | RN-8 |  |
| AD8027ART-R2 | 250 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 6 -Lead SOT-23 | RT-6 | H4B |
| AD8027ART-REEL | 10,000 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 6 -Lead SOT-23 | RT-6 | H4B |
| AD8027ART-REEL7 | 3,000 | $-40^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ | 6 -Lead SOT-23 | RT-6 | H4B |

## AD8027

NOTES

| A88027 |
| ---: |

NOTES


[^0]:    ${ }^{1}$ Protected by U.S. Patents No. 6,486,737 B1, No. 6,518,842 B1

